A Parasitics Extraction and Network Reduction Algorithm for Analog VLSI

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Abstract—This paper discusses an algorithm for the extraction of circuit parasitics in integrated circuits using classical transmission line models. This gives a better account of the dc and ac characteristics of interconnects than models incorporating exclusively either the R or C components. We also detail a network reduction technique used to simplify networks at all specified accuracies to manageable complexities, especially for large VLSI circuits. The model and circuit reduction algorithms are applied to practical sample circuits. Results of simulations illustrating the reduction in circuit complexity and the degree of modeling accuracy by these methods are also given.

I. INTRODUCTION

WITH THE advancement of VLSI technologies, circuit designers require more accurate prediction of the effect of integrated circuit parasitics, such as gate resistances and capacitances [1]. In particular, analog circuits constructed in a short channel MOS technology require accurate prediction of parasitics to prevent mismatch, undesirable crosstalk, and uncontrollable effects at sensitive nodes.

Various papers have been published on this topic. Certain algorithms [2]-[7] involve calculating interconnect resistances using general Laplace equations, conformal transformations, finite elements and differences, or geometric heuristics. They all present varying degrees of accuracy and speed of calculation. Others [8]-[13] include parasitic capacitance calculation in their algorithms as well. Networks at all specified accuracies to manageable R and C of interconnect parasitics separately and independently, which is not strictly correct.

In [14], a model is presented which considers interconnects as a RC transmission line. The model gives accurate simulation results for simple lines but provides no solution to the complexity problem encountered when it is applied to large-scale networks because of their higher order.

In the extraction of complex VLSI circuits, after accurately modeling the parasitics, a network reduction algorithm is necessary to simplify them. There should also be a way to control the accuracy of the simplified network at user specified frequencies. This will ensure that no unnecessary accuracy is used in the model when it is uncalled for.

This paper presents a transmission line model for parasitics extraction, coupled with a network simplification algorithm in order to work efficiently even with big VLSI circuit layouts. Extraction and network reduction are carried out at accuracies specified by the operator.

II. MODELING OF TRANSMISSION LINE INTERCONNECTS

It is necessary to use an accurate model to describe circuit parasitics. From transmission line theory, for a line of length D and at a given frequency ω, exact equivalent T and Pi networks can be found. These networks have the form shown in Fig. 1.

\[ Z_0 = \sqrt{(R_0 + j\omega C_0) / (G_0 + j\omega L_0)} \] is the characteristic impedance of the line, \( \gamma = \sqrt{(R_0 + j\omega L_0) / (G_0 + j\omega C_0)} \) is the propagation function, \( R_0 \), \( L_0 \), \( G_0 \), and \( C_0 \) are the resistance, inductance, conductance, and capacitance per unit length, respectively.

We notice that, for \( |\gamma D| << 1 \):

\[ \sinh \gamma D = \gamma D \] \hspace{1cm} (1)

\[ \cosh \gamma D = 1 \] \hspace{1cm} (2)

\[ \tanh \frac{\gamma D}{2} = \frac{\gamma D}{2} \] \hspace{1cm} (3)

So

\[ Z_0 \times \tanh \frac{\gamma D}{2} = \frac{(R_0 + j\omega L_0) \times D}{2} \] \hspace{1cm} (4)

\[ Z_0 = \frac{1}{\sinh \gamma D} \cdot \frac{(G_0 + j\omega C_0) \times D}{2} \] \hspace{1cm} (5)

We can, therefore, replace the T and Pi networks in Fig. 1 by simplified models, as illustrated in Fig. 2.

These simplified models can further be approximated by the use of only R and C elements, i.e., by neglecting the L and G components. Such approximations will incur an error of approximation, global error (D), which can be calculated as follows.

In analog VLSI, \( \omega L_0 \ll R_0 \) and \( G_0 \ll \omega C_0 \) are generally true (a set of typical values are: \( \omega = 2 \pi \times 100 \text{ MHz}, L_0 = 10^{-15} \text{ H/\mu m}, R_0 = 0.01 \text{ \Omega/\square}, G_0 = 10^{-16} \text{ \Omega^{-1} \square}, C_0 = 10^{-16} \text{ F/\mu m^2} \)). Then:

\[ Z_0 = \sqrt{\frac{R}{\omega C_0}} = \sqrt{\frac{R_0}{\omega C_0}} \times e^{(1/j\pi/4)} \] \hspace{1cm} (6)

\[ \gamma = \sqrt{\frac{j\omega R_0 C_0}{\omega C_0}} = \sqrt{\omega R_0 C_0} \times e^{(1/j\pi/4)} \] \hspace{1cm} (7)

\[ = \frac{\omega R_0 C_0}{2} \times (1 + j) = \alpha + j\beta. \] \hspace{1cm} (8)

Then:

\[ \alpha = \beta = \sqrt{\frac{\omega R_0 C_0}{2}} \] \hspace{1cm} (9)

\[ \sinh \gamma D = \sinh \beta D \cos \beta D + j \cosh \beta D \sin \beta D. \] \hspace{1cm} (10)
The error when approximating \( \sinh \gamma D = \gamma D = \alpha D + j\beta D \) is

\[
\text{error (R)} = 1 - \frac{\beta D}{\sinh \beta D \cos \beta D}
\]

\[
\text{error (Im)} = 1 - \frac{\beta D}{\cosh \beta D \sin \beta D}
\]

where \( \text{error (R)} \) and \( \text{error (Im)} \) are errors in the real and imaginary parts of the approximation, respectively. We then define

\[
\text{global error (D)} = \max \{ \text{error (R)}, \ \text{error (Im)} \}.
\]

Since \( \tanh \gamma D = (\sinh \gamma D / \cosh \gamma D) \), and \( \cosh x = 1 \) is a much better approximation than \( \sinh x = x \) (gradient of \( \cosh \) is much smaller than \( \sinh \) at the origin), the error of \( \tanh \gamma D = \gamma D \) is lower than that of \( \sinh \gamma D = \gamma D \). The error of approximating \( \tanh (\gamma D / 2) = (\gamma D / 2) \) is, therefore, limited by the expression of global error \( (D) \) derived for \( \sinh \gamma D = \gamma D \) above.

To give an example, let us take the polysilicon transmission line in SCMOS 2.0-\( \mu \text{m} \) technology [15] which has: \( R_0 = 25.3 \) \( \Omega \)/square, \( C_0 = 39 \text{ aF/}\mu \text{m}^2 \). Then, at \( \omega = 2\pi \times 100 \text{ MHz}, \beta = 5.60 \times 10^{-4} \text{ rad/}\mu \text{m} \). At these values:

For \( D = 50 \mu \text{m} \), global error \( (D) = 0.5\% \)

For \( D = 500 \mu \text{m} \), global error \( (D) = 4.99\% \).
will have their capacitance values adjusted according to measured values for the particular technology in use. The correction is linear in terms of the length of the edge in question. Admittedly this approximation is not as accurate as methods such as the Laplace equations, but is sufficient for the purpose of providing a simple enough circuit that predicts the influence of integrated circuit parasitics on analog circuit performance to within a given error tolerance level. An example for the derivation of a two-pronged line is given in Fig. 4.

III. RC NETWORK REDUCTION

The transmission line model provides us with an accurate way to calculate circuit parasitics. However, the network thus extracted from actual VLSI circuits would contain too many branches to be practical for any simulation purposes. So there is a need to be able to simplify the extracted network, preferably at user controlled accuracy, as well.

Using classical network theories, we know that for any star configuration, there exists an equivalent delta configuration with one less node.

In Fig. 5, we have

\[ Z_y = z_1 \times z_2 \times \sum_{i=1}^{n} \frac{1}{z_i} = \text{Re}(Z_y) + j \text{Im}(Z_y). \]  

(14)

This simple formula gives an exact transformation of star to delta networks. Here, the reader's attention is called to the fact that the technique works for the frequency domain only. For our network reduction algorithm, we will recursively employ this star-delta conversion to simplify the extracted circuit. After each star-delta conversion, we will try to simplify the resulting delta network to one consisting of only purely resistive and purely capacitive branches. This is done by simply neglecting the smaller (in terms of admittance) component of the real or imaginary parts.

An example dealing with a symmetrical 4-pronged line with only R and C branches is given in Fig. 6.

For a branch simplified to a resistor

\[ \text{error}(R_{\text{branch}}) = \left( \frac{\text{Im}(Z_y)}{\text{Re}(Z_y)} \right)_{\text{branch}}. \]  

(15)

For a branch simplified to a capacitor

\[ \text{error}(C_{\text{branch}}) = \left( \frac{\text{Re}(Z_y)}{\text{Im}(Z_y)} \right)_{\text{branch}}. \]  

(16)

We then define the overall error, called maximum error, to be:

\[ \text{maximum error} = \max (\max_{\text{all branches}} (\text{error}(R_{\text{branch}}))), \max_{\text{all branches}} (\text{error}(C_{\text{branch}}))). \]  

(17)

When the maximum error exceeds a specified threshold value, the conversion and subsequent approximation to purely R and C branches will not be carried out. Notice that the complex impedance simulation line model of the interconnect is used as the starting point for all simplifications. This ensures that the errors calculated are the exact relative errors between the unsimplified and simplified interconnect models. This means that
any impedance measurement taken from the simplified interconnect model will match a similar measurement taken from the unsimplified model to within the user specified error at the user specified frequency.

IV. ALGORITHM FOR EXTRACTION AND NETWORK REDUCTION

Using the transmission line and network simplification theories as explained previously, we arrive at our parasitics extraction algorithm for Manhattan designs.

a) Find all intersections of line elements and cut up the lines at the intersecting coordinates.

b) Given the working frequency and error tolerance for network reduction (these can be user inputs), calculate the maximum line segment dimensions, for each layer material, to be extracted.

c) Using the values from b), find interconnect lines and other parasitic elements whose dimensions are too big and divide them into smaller pieces whose length and width are both below the maximum allowable feature size.

d) Extract connectivity information and number nodes accordingly.

e) For each rectangle, generate line elements using the T transmission line model with exact complex impedance values as shown in Fig. 1 for each of its edges that is a connection node. Each line element’s components are calculated for the half-rectangle that the current sees flowing from the edge to the geometric center of the full rectangle. Then connect the line element branches using connectivity information from d).

f) Simplify the network using the star-delta conversion formulas recursively on every node until the error threshold given by the user governing the reducibility of any star configuration prevents any further reduction.

V. IMPLEMENTATION AND RESULTS

The transmission line model and RC network reduction algorithm are implemented in a C language program of approximately 2700 lines in source code. The program assumes the input to be in the Magic layout file format and produces a SPICE simulation deck as output.

The program was run on the Magic layout file of several simple layouts, whose responses are known. Parameters such as the error threshold and working frequency were varied to compare their influence on the accuracy of the extracted circuit. The following are the results from the extraction of two typical layouts. In both cases, the transmission line model was calculated at an error tolerance level of 10%, with the working frequency at 100 MHz. The network reduction algorithm was carried out up to a 10% error threshold. The accuracy of the reduced network is compared to the unreduced model, extracted at 10% accuracy, in terms of input node impedance as seen from outside the circuit at specific nodes, and the relative percentage errors are plotted. This type of comparison is suitable for the prediction of signal behavior on a transmission line that goes on an I/O node to drive a transistor, for example.

Example #1 (Fig. 7) shows how a complex RC network is effectively reduced to the minimum allowed by the star-delta conversion method, i.e., \((n \times (n - 1)/2)\) branches for \(n\) I/O nodes. The number of RC branches and nodes was thus reduced by a factor of about 4.7. This example layout is typical of power or clock lines with numerous distribution points. When the star-delta conversion/reduction process stops because the error threshold has been reached, a further reduction of the circuit can also be envisaged by combining I/O ports interconnected by impedances which are small enough to be considered as practical short circuits. In such cases, the test that ensures the accuracy of the process is tied in with the sensitivity of the simulator accuracy and user specified voltage and current accuracies.

Example #2 (Fig. 8) illustrates the effect of different characteristic impedance values of a layer type on the complexity and accuracy of the extracted SPICE file (i.e., the \(R\) and \(C\) were increased 10 fold arbitrarily to simulate the change in layer and characteristic impedance).

While the two frequency plots above are given for the range of frequencies from 1 MHz to 1 GHz, the part of the curves beyond 100 MHz are not to be taken as literally predicting excellent performance at microwave frequency ranges. What the graphs do predict is that the reduced networks accurately represent the behavior of transmission lines at least up till the working frequency (or frequencies) at which the network was extracted and reduced, and this to within a user specified error tolerance level.

From these examples and others, it is noted that, at relatively high error thresholds for the reduction algorithm (up to even 50% in simple cases), the extracted circuits still present remarkable accuracy at frequencies up to the working frequency. This indicates that error thresholds can be relaxed quite generously in lieu of more simplicity in the extracted circuit and simulation speed.
VI. CONCLUSION

The transmission line model can be used effectively and accurately in the extraction of parasitics, and affords a better account of the effects of parasitics in analog integrated circuits. The network reduction technique presented is attractive in that it can accommodate a compromise between speed and accuracy during simulation and produce simulation parameters accordingly.

Although this algorithm is written in the Magic context, the general approach in applying transmission line theory and network simplification to parasitics extraction can be extended to other CAD layout data bases with the Manhattan design rule.

REFERENCES


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